



TPS727xx 250-mA, Ultralow I_Q , Fast Transient Response, RF Low-Dropout Linear Regulator

1 Features

- Very Low Dropout:
 - 65 mV Typical at 100 mA
 - 130 mV Typical at 200 mA
 - 163 mV Typical at 250 mA
- 2% Accuracy Over Load, Line, Temperature
- Ultralow I_Q : 7.9 μ A
- Excellent Load Transient Performance: ± 50 mV for 200 mA Loading and Unloading Transient
- Available in Fixed-Output Voltages From 0.9 V to 5 V Using Innovative Factory EEPROM Programming
- High PSRR: 70 dB at 1 kHz
- Stable with a 1.0- μ F Ceramic Capacitor
- Thermal Shutdown and Overcurrent Protection
- Available in 4-Ball, 0.4-mm Pitch Wafer-Level Chip Scale and 1.5-mm $\times$ 1.5-mm SON Packages

2 Applications

- Wireless Handsets, Smart Phones, PDAs
- MP3 Players and Other Handheld Products
- Wireless LAN, Bluetooth[®], Zigbee[®]
- Remote Controls
- Portable Consumer Products

3 Description

The TPS727xx family of low-dropout (LDO) linear regulators are ultralow quiescent current LDOs with excellent line and ultra-fast load transient performance and are designed for power-sensitive applications. The LDO output voltage level is preset by the use of innovative factory EEPROM programming. A precision band-gap and error amplifier provides overall 2% accuracy over load, line, and temperature extremes. The TPS727xx family is available in 1.5-mm $\times$ 1.5-mm SON and wafer chip-scale (WCSP) packages that make the devices ideal for handheld applications. This family of devices is fully specified over a temperature range of $T_J = -40^\circ\text{C}$ to $+125^\circ\text{C}$.

Device Information

PART NUMBER	PACKAGE	BODY SIZE (NOM)
TPS727xxDSE	WSON (6)	1.50 mm $\times$ 1.50 mm
TPS727xxYFF	DSBGA (4)	1.00 mm $\times$ 1.00 mm

(1) For all available packages, see the orderable addendum at the end of the datasheet.

TYPICAL APPLICATION CIRCUIT

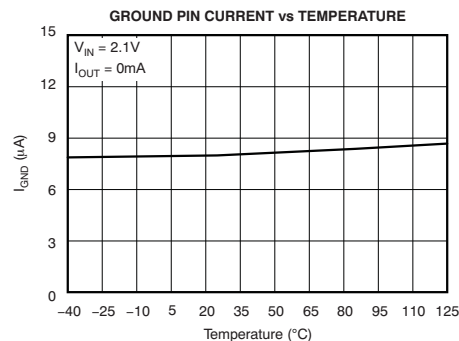
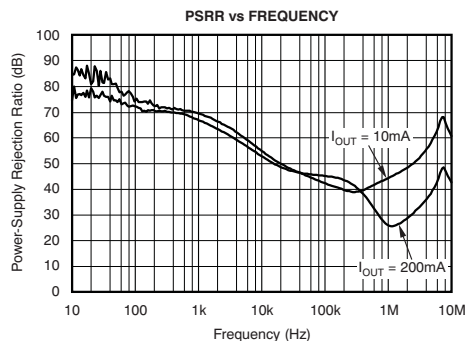
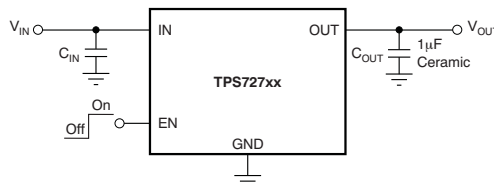


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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision D (February 2014) to Revision E	Page
• Added TPS727105 to document	1
• Changed <i>terminal</i> to <i>pin</i> throughout document	1
• Updated Device Information table to current standards	1
• Changed Pin Configurations note	4
• Changed Pin Functions table: reordered table by pin name, added I/O column	4
• Updated Handling Ratings table to current standard	5
• Changed Thermal Information table: updated symbols.....	5
• Deleted <i>new generation</i> from first sentence of <i>Overview</i> section	11
• Added note to Applications and Implementation section.....	13

Changes from Revision C (January, 2011) to Revision D	Page
• Changed format to meet latest data sheet standards; added new sections and moved existing sections.....	1
• Deleted pinout diagrams from front page; see <i>Pin Configurations and Functions</i> section.	1
• Changed Pin Configurations section and moved to Pin Configurations and Functions section	4
• Changed note in Pin Configurations and Functions section.	4
• Deleted Figure 26 and Figure 27	17

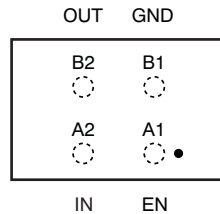
Changes from Revision B (April, 2010) to Revision C	Page
• Updated YFF front page pin drawing to show pin locations.....	1
• Revised Pin Configurations section	4
• Changed graph title for Figure 6	7

Changes from Revision A (September, 2009) to Revision B	Page
• Updated <i>Features</i> list	1
• Changed title of data sheet.....	1
• Changed footnote 2 to <i>Absolute Maximum Ratings</i> table	5
• Revised numerous specifications and parameters in <i>Electrical Characteristics</i> table	6
• Revised operating parameters for Figure 4	7
• Replaced Figure 5	7
• Added operating parameters to Figure 6	7
• Updated Figure 9	7

5 Pin Configurations and Functions

TPS72715, TPS72718, TPS72728, TPS72748

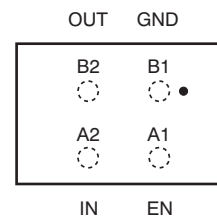
YFF Package DSBGA-4 (Top View)



See note.

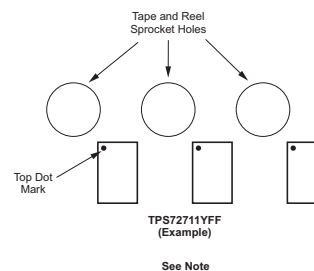
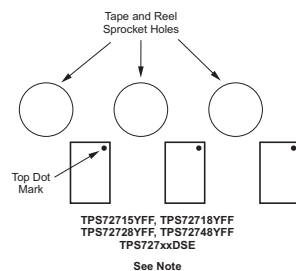
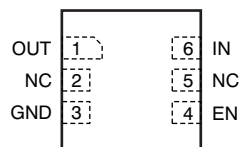
All Other TPS727xx Devices

YFF Package DSBGA-4 (Top View)



See note.

DSE Package 1,5mm × 1,5mm WSON-6 (Top View)



NOTE

The **EN** pin is marked with a dot for the 1.5-V, 1.8-V, 2.8-V, and 4.8-V versions of the YFF package. The **GND** pin is marked with a dot for all other voltage versions of the YFF package. Refer to YFF0004 Package Outline page included at the end of this document for dimensions of the YFF package. On the package outline, the shaded box indicates the location of ball A1 and does not correlate to any marking on the topside of the physical package.

Pin Functions

PIN			I/O	DESCRIPTION
NAME	YFF	DSE		
EN	A1	4	I	Enable pin. Driving EN over 0.9 V turns on the regulator. Driving EN below 0.4 V puts the regulator into shutdown mode, thus reducing the operating current to 120 nA, nominal.
GND	B1	3	—	Ground pin.
IN	A2	6	I	Input pin. A small capacitor is needed from this pin to ground to assure stability. See Input and Output Capacitor Requirements in the <i>Application Information</i> section for more details.
NC	—	2, 5	—	No connection. This pin can be tied to ground to improve thermal dissipation.
OUT	B2	1	O	Regulated output voltage pin. A small 1-μF ceramic capacitor is needed from this pin to ground to assure stability. See Input and Output Capacitor Requirements in the <i>Application Information</i> section for more details.

6 Specifications

6.1 Absolute Maximum Ratings

At $T_J = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$ (unless otherwise noted). All voltages are with respect to GND.⁽¹⁾

	MIN	MAX	UNIT
Input voltage range, V_{IN}	-0.3	+6.0	V
Enable voltage range, V_{EN}	-0.3	+6.0 ⁽²⁾	V
Output voltage range, V_{OUT}	-0.3	+6.0	V
Maximum output current, I_{OUT}	Internally limited		
Output short-circuit duration	Indefinite		
Operating junction temperature range, T_J	-55	+150	$^{\circ}\text{C}$

- (1) Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.
- (2) V_{EN} absolute maximum rating is V_{IN} or 6.0 V, whichever is less.

6.2 Handling Ratings

		MIN	MAX	UNIT
T_{stg}	Storage temperature range	-55	+150	$^{\circ}\text{C}$
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾	2	kV
		Charged device model (CDM), per JEDEC specification JESD22-C101, all pins ⁽²⁾	500	V

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

Over operating junction temperature range (unless otherwise noted).

	MIN	NOM	MAX	UNIT
V_{IN} Input voltage	2		5.5	V
I_{OUT} Output current	0		250	mA
T_J Operating junction temperature range	-40		+125	$^{\circ}\text{C}$

6.4 Thermal Information

THERMAL METRIC ⁽¹⁾		TPS727xx		UNITS
		DSE	YFF	
		6 PINS	4 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	190.5	160	$^{\circ}\text{C/W}$
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	94.9	75	
$R_{\theta JB}$	Junction-to-board thermal resistance	149.3	76	
Ψ_{JT}	Junction-to-top characterization parameter	6.4	3	
Ψ_{JB}	Junction-to-board characterization parameter	152.8	74	
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance ⁽²⁾	N/A	N/A	

- (1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, [SPRA953](#).
- (2) θ_{Jcbot} is not applicable because there is no thermal pad.

6.5 Electrical Characteristics

Over operating temperature range ($T_J = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$), $V_{IN} = V_{OUT(TYP)} + 0.3\text{ V}$ or 2.0 V , whichever is greater; $I_{OUT} = 10\text{ mA}$, $V_{EN} = 0.9\text{ V}$, and $C_{OUT} = 1.0\text{ }\mu\text{F}$ (unless otherwise noted). Typical values are at $T_J = +25^{\circ}\text{C}$.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{IN}	Input voltage range		2.0		5.5	V
V_O	Output voltage range		0.9		5.0	V
$V_{OUT}^{(1)}$	DC output accuracy	$T_J = +25^{\circ}\text{C}$	-2.5		+2.5	mV
		$V_{OUT} + 0.3\text{ V} \leq V_{IN} \leq 5.5\text{ V}$, $0\text{ mA} \leq I_{OUT} \leq 200\text{ mA}$	-2.0%	$\pm 1.0\%$	+2.0%	
		$V_{OUT} + 0.3\text{ V} \leq V_{IN} \leq 5.5\text{ V}$, $0\text{ mA} \leq I_{OUT} \leq 250\text{ mA}$		$\pm 1.0\%$		
ΔV_{OUT}	Load transient	1 mA to 200 mA or 200 mA to 1 mA in 1 μs , $C_{OUT} = 1\text{ }\mu\text{F}$		± 50.0		mV
		1 mA to 250 mA or 250 mA to 1 mA in 1 μs , $C_{OUT} = 1\text{ }\mu\text{F}$		± 65		mV
$\Delta V_O / \Delta V_{IN}$	Line regulation	$V_{OUT(NOM)} + 0.3\text{ V} \leq V_{IN} \leq 5.5\text{ V}$, $I_{OUT} = 10\text{ mA}$		8		$\mu\text{V/V}$
$\Delta V_O / \Delta I_{OUT}$	Load regulation	$0\text{ mA} \leq I_{OUT} \leq 250\text{ mA}$		20		$\mu\text{V/mA}$
V_{DO}	Dropout voltage ⁽²⁾	$V_{IN} = 0.98 \times V_{OUT(NOM)}$, $I_{OUT} = 10\text{ mA}$		6.5		mV
		$V_{IN} = 0.98 \times V_{OUT(NOM)}$, $I_{OUT} = 50\text{ mA}$		32.5		mV
		$V_{IN} = 0.98 \times V_{OUT(NOM)}$, $I_{OUT} = 100\text{ mA}$		65		mV
		$V_{IN} = 0.98 \times V_{OUT(NOM)}$, $I_{OUT} = 200\text{ mA}$		130	200	mV
		$V_{IN} = 0.98 \times V_{OUT(NOM)}$, $I_{OUT} = 250\text{ mA}$		162.5		mV
I_{CL}	Output current limit	$V_{OUT} = 0.9 \times V_{OUT(NOM)}$	300	400	550	mA
I_{GND}	Ground pin current	$I_{OUT} = 0\text{ mA}$, $T_J = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$		7.9	12	μA
		$I_{OUT} = 200\text{ mA}$		110		μA
		$I_{OUT} = 250\text{ mA}$		130		μA
I_{SHDN}	Shutdown current (I_{GND})	$V_{EN} \leq 0.4\text{ V}$, $V_{IN} = 2\text{ V}$, $T_J = +25^{\circ}\text{C}$		0.12		μA
		$V_{EN} \leq 0.4\text{ V}$, $2.0\text{ V} < V_{IN} \leq 4.5\text{ V}$, $T_J = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$		0.55	2	μA
PSRR	Power-supply rejection ratio	$V_{IN} = 2.3\text{ V}$, $V_{OUT} = 1.8\text{ V}$, $I_{OUT} = 10\text{ mA}$	f = 10 Hz	85		dB
			f = 100 Hz	75		dB
			f = 1 kHz	70		dB
			f = 10 kHz	55		dB
			f = 100 kHz	40		dB
			f = 1 MHz	45		dB
V_N	Output noise voltage	BW = 100 Hz to 100 kHz, $V_{IN} = 2.1\text{ V}$, $V_{OUT} = 1.8\text{ V}$, $I_{OUT} = 10\text{ mA}$		33.5		μV_{RMS}
t_{STR}	Startup time ⁽³⁾	$C_{OUT} = 1.0\text{ }\mu\text{F}$, $0 \leq I_{OUT} \leq 250\text{ mA}$		100		μs
V_{HI}	Enable pin high (enabled)		0.9		V_{IN}	V
V_{LO}	Enable pin low (disabled)		0		0.4	V
I_{EN}	Enable pin current	EN = 5.5 V		40	500	nA
UVLO	Undervoltage lock-out	V_{IN} rising	1.85	1.90	1.95	V
T_{SD}	Thermal shutdown temperature	Shutdown, temperature increasing		+160		$^{\circ}\text{C}$
		Reset, temperature decreasing		+140		$^{\circ}\text{C}$
T_J	Operating junction temperature		-40		+125	$^{\circ}\text{C}$

(1) The output voltage is programmed at the factory.

(2) V_{DO} is measured for devices with $V_{OUT(NOM)} \geq 2.35\text{ V}$ so that $V_{IN} \geq 2.3\text{ V}$.

(3) Startup time: time from EN assertion to $0.98 \times V_{OUT(NOM)}$.

6.6 Typical Characteristics

Over operating temperature range ($T_J = -40^\circ\text{C}$ to $+125^\circ\text{C}$), $V_{IN} = V_{OUT(TYP)} + 0.3\text{ V}$ or 2.0 V , whichever is greater; $I_{OUT} = 10\text{ mA}$, $V_{EN} = V_{IN}$, and $C_{OUT} = 1.0\text{ }\mu\text{F}$ (unless otherwise noted). Typical values are at $T_J = +25^\circ\text{C}$.

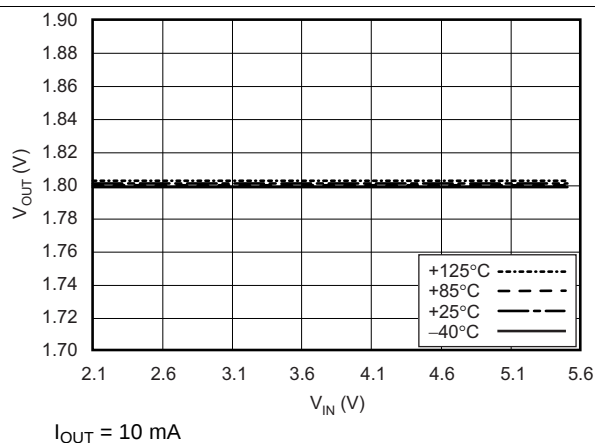


Figure 1. Line Regulation (TPS72718)

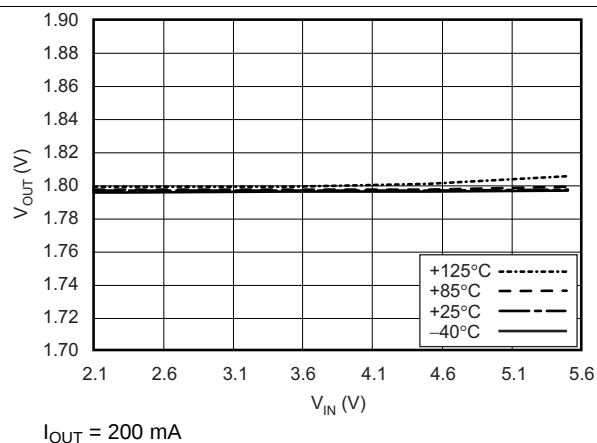


Figure 2. Line Regulation (TPS72718)

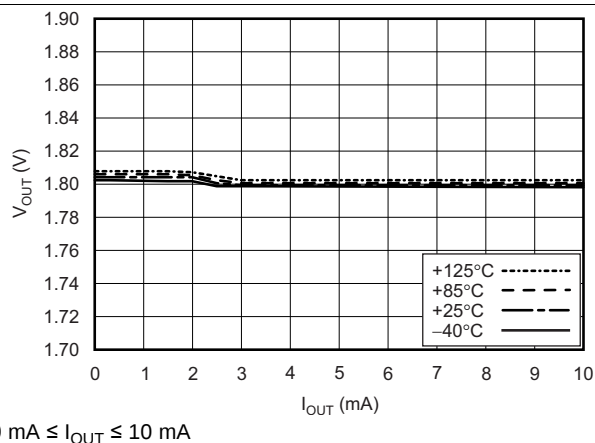


Figure 3. Load Regulation Under Light Loads (TPS72718)

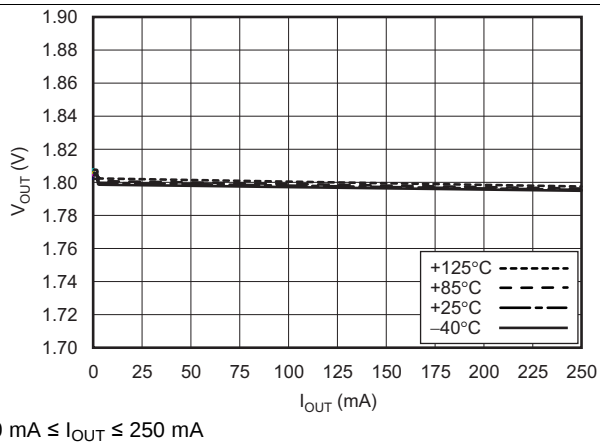


Figure 4. Load Regulation (TPS72718)

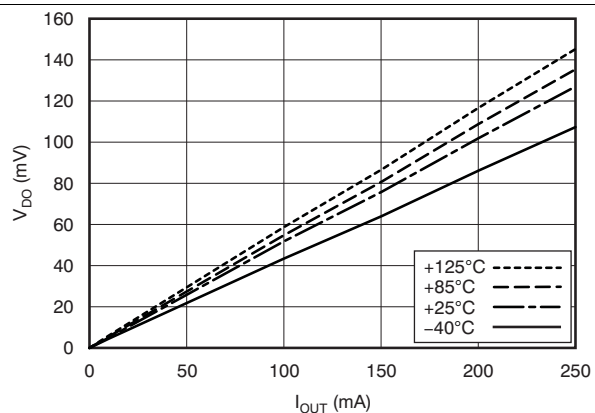


Figure 5. Dropout Voltage vs Output Current (TPS72750)

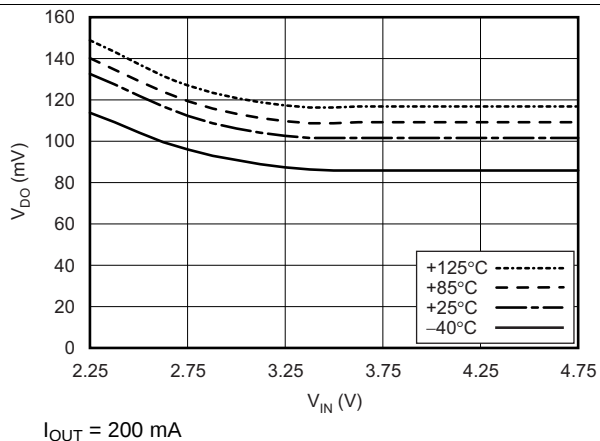


Figure 6. Dropout Voltage vs Input Voltage

Typical Characteristics (continued)

Over operating temperature range ($T_J = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$), $V_{IN} = V_{OUT(TYP)} + 0.3\text{ V}$ or 2.0 V , whichever is greater; $I_{OUT} = 10\text{ mA}$, $V_{EN} = V_{IN}$, and $C_{OUT} = 1.0\text{ }\mu\text{F}$ (unless otherwise noted). Typical values are at $T_J = +25^{\circ}\text{C}$.

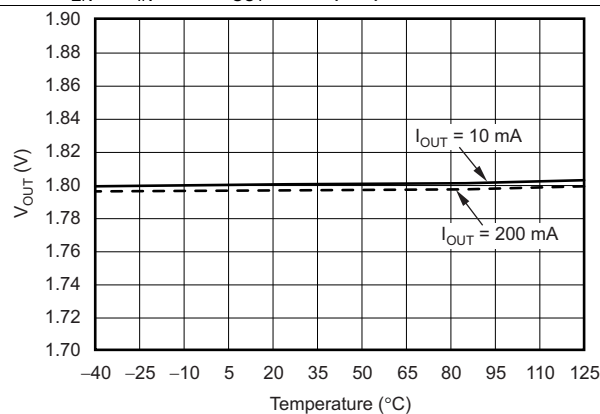
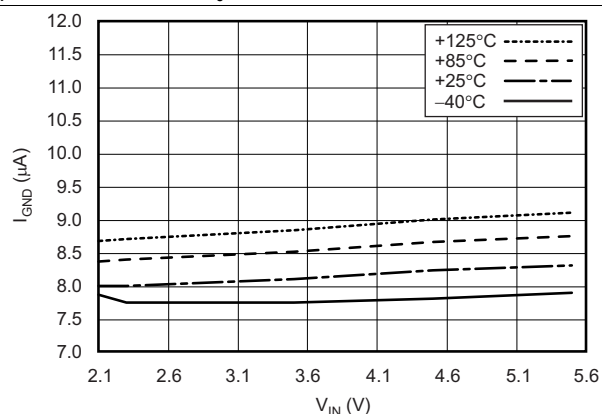
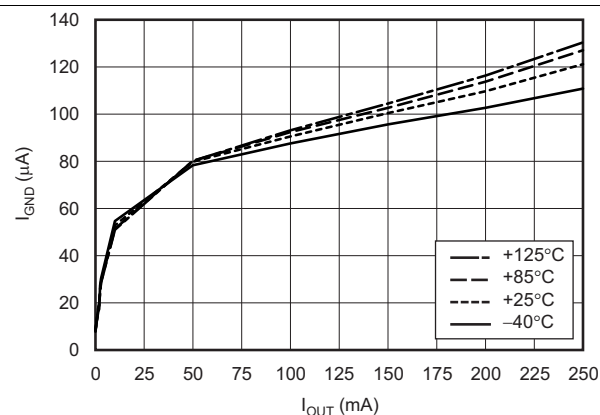


Figure 7. Output Voltage vs Temperature (TPS72718)



$I_{OUT} = 0\text{ mA}$

Figure 8. Ground Pin Current vs Input Voltage (TPS72718)



$0\text{ mA} \leq I_{OUT} \leq 250\text{ mA}$

Figure 9. Ground Pin Current vs Load (TPS72718)

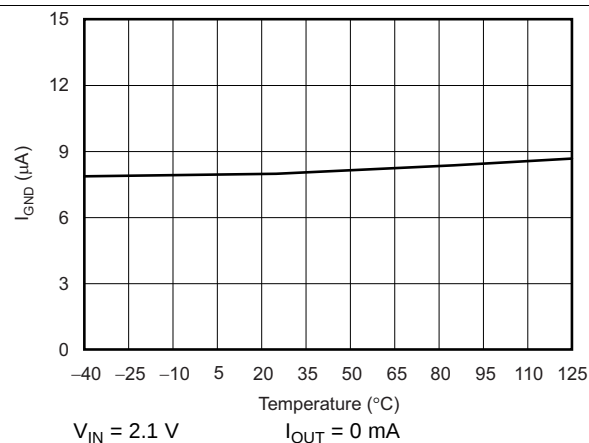


Figure 10. Ground Pin Current vs Temperature (TPS72718)

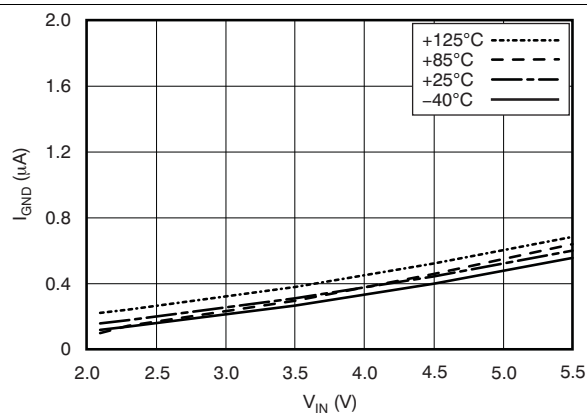


Figure 11. Shutdown Current vs Input Voltage (TPS72718)

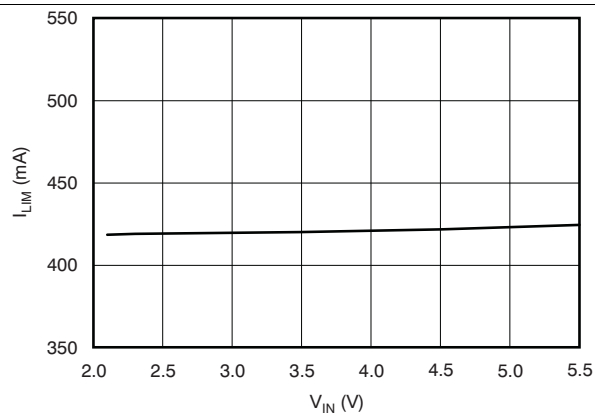


Figure 12. Current Limit vs Input Voltage (TPS72718)

Typical Characteristics (continued)

Over operating temperature range ($T_J = -40^\circ\text{C}$ to $+125^\circ\text{C}$), $V_{IN} = V_{OUT(TYP)} + 0.3\text{ V}$ or 2.0 V , whichever is greater; $I_{OUT} = 10\text{ mA}$, $V_{EN} = V_{IN}$, and $C_{OUT} = 1.0\text{ }\mu\text{F}$ (unless otherwise noted). Typical values are at $T_J = +25^\circ\text{C}$.

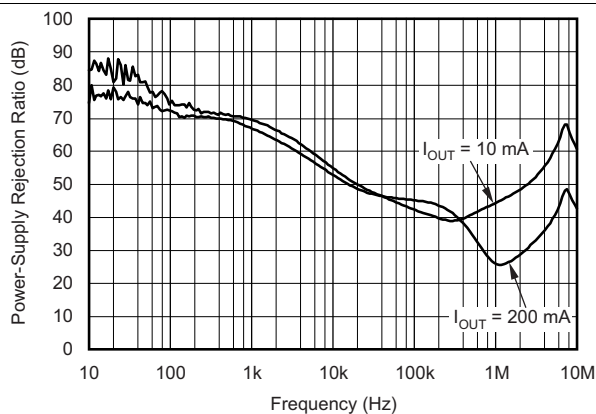


Figure 13. PSRR vs Frequency
($V_{IN} - V_{OUT} = 0.5\text{ V}$, TPS72718)

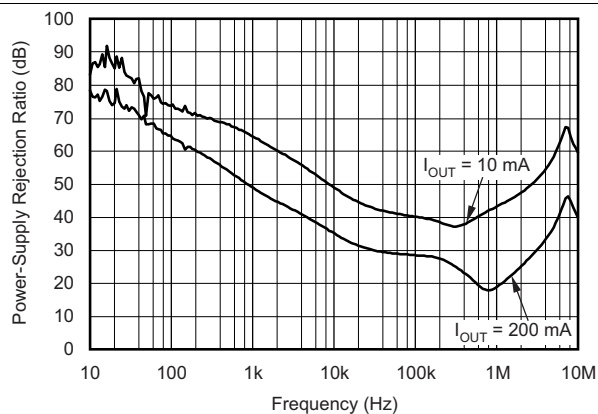


Figure 14. PSRR vs Frequency
($V_{IN} - V_{OUT} = 0.3\text{ V}$, TPS72718)

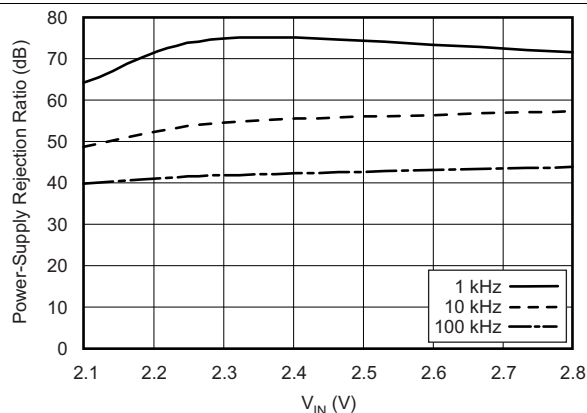


Figure 15. PSRR vs Input Voltage
(TPS72718)

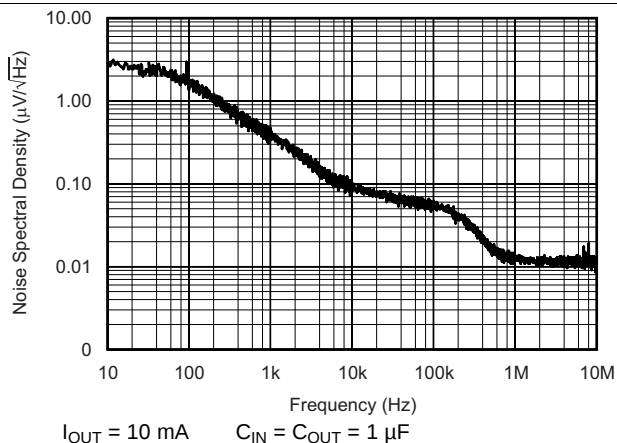


Figure 16. Output Spectral Noise Density vs Output Voltage
(TPS72718)

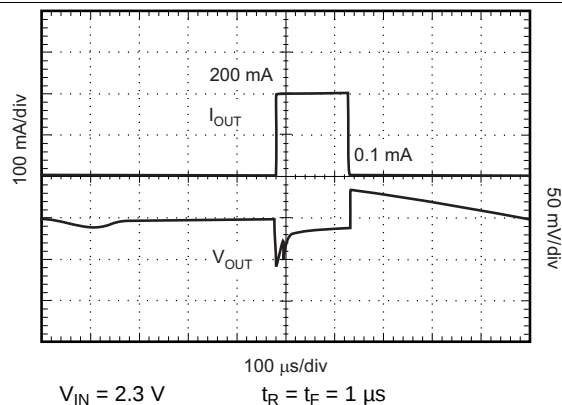


Figure 17. Load Transient Response: 0.1 mA to 200 mA
(TPS72718)

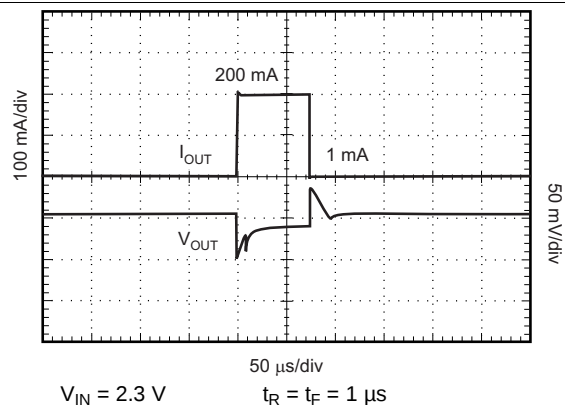


Figure 18. Load Transient Response: 1 mA to 200 mA
(TPS72718)

Typical Characteristics (continued)

Over operating temperature range ($T_J = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$), $V_{IN} = V_{OUT(TYP)} + 0.3\text{ V}$ or 2.0 V , whichever is greater; $I_{OUT} = 10\text{ mA}$, $V_{EN} = V_{IN}$, and $C_{OUT} = 1.0\text{ }\mu\text{F}$ (unless otherwise noted). Typical values are at $T_J = +25^{\circ}\text{C}$.

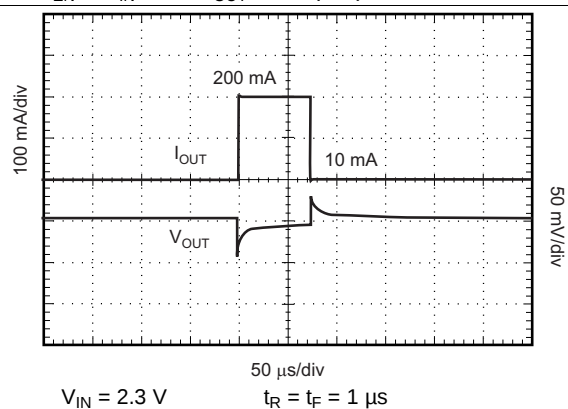


Figure 19. Load Transient Response: 10 mA to 200 mA (TPS72718)

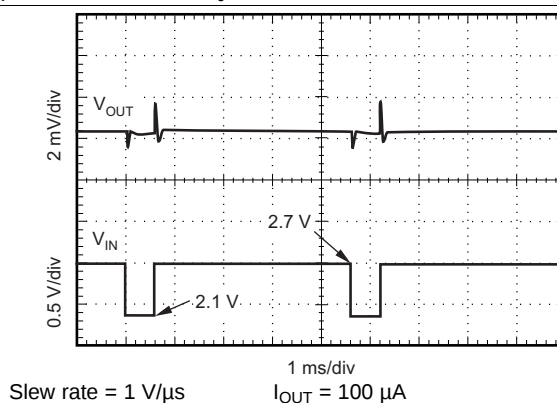


Figure 20. Line Transient Response (TPS72718)

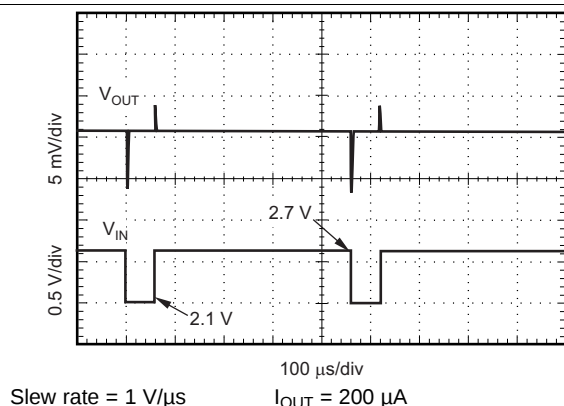


Figure 21. Line Transient Response (TPS72718)

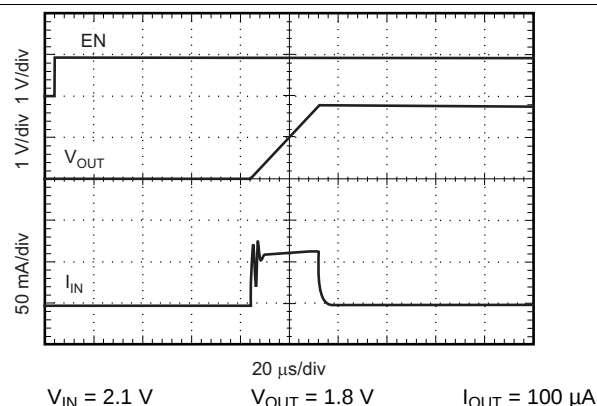


Figure 22. V_{IN} Inrush Current (TPS72718)

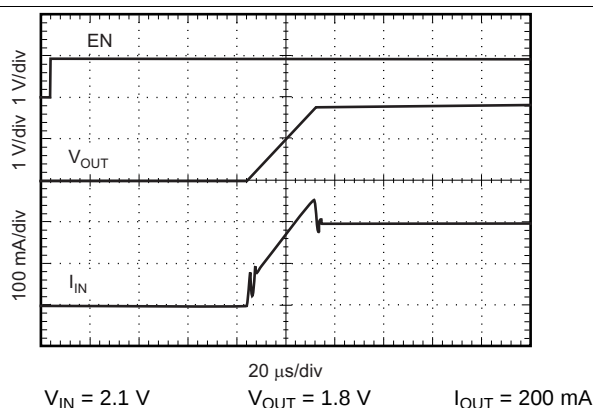


Figure 23. V_{IN} Inrush Current (TPS72718)

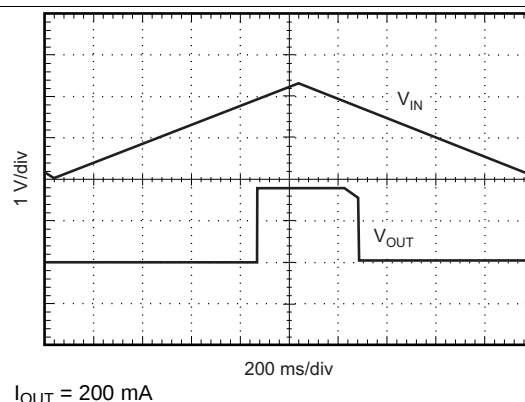


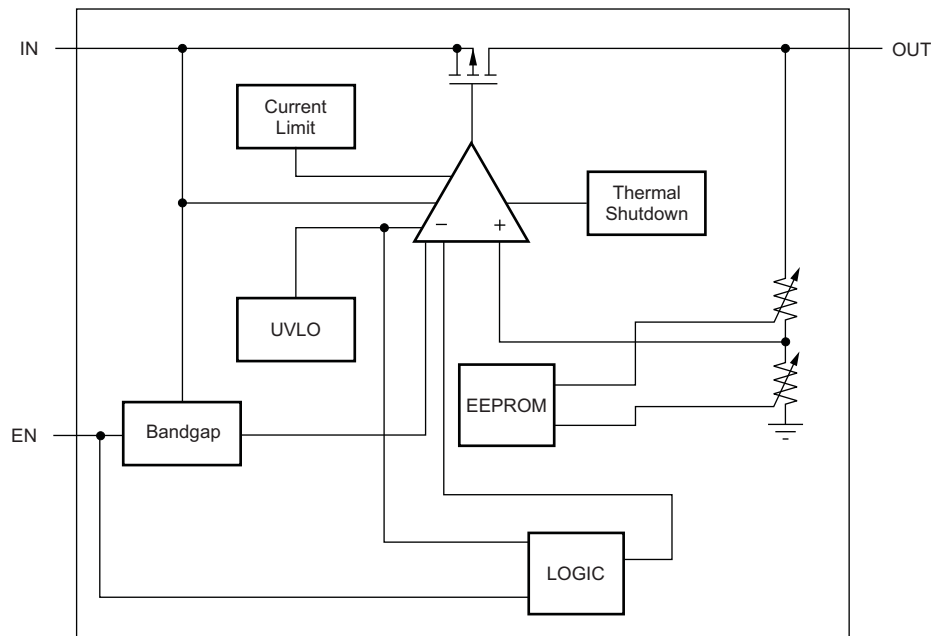
Figure 24. V_{IN} Ramp Up, Ramp Down Response (TPS72718)

7 Detailed Description

7.1 Overview

The TPS727xx devices belong to a family of LDO regulators that consume extremely low quiescent current while simultaneously delivering excellent PSRR with very little headroom ($V_{IN} - V_{OUT}$ differential voltage), and very good transient response. These features, combined with low noise without a noise reduction pin in an ultrasmall package, make these devices ideal for portable applications. This family of regulators offers sub-band-gap output voltages, current limit and thermal protection, and is fully specified from -40°C to $+125^{\circ}\text{C}$.

7.2 Functional Block Diagram



7.3 Feature Description

7.3.1 Internal Current Limit

The TPS727xx internal current limit helps protect the regulator during fault conditions. During current limit, the output sources a fixed amount of current that is largely independent of output voltage. In such a case, the output voltage is not regulated and is $V_{OUT} = I_{LIMIT} \times R_{LOAD}$. The PMOS pass transistor dissipates $(V_{IN} - V_{OUT}) \times I_{LIMIT}$ until thermal shutdown is triggered and the device is turned off. As the device cools down, it is turned on by the internal thermal shutdown circuit. If the fault condition continues, the device cycles between current limit and thermal shutdown. See the [Thermal Protection](#) section for more details.

The PMOS pass element in the TPS727xx has a built-in body diode that conducts current when the voltage at the OUT pin exceeds the voltage at the IN pin. This current is not limited, so if extended reverse voltage operation is anticipated, external limiting to 5% of rated output current is recommended.

7.3.2 Soft Start

The startup current is given by [Equation 1](#):

$$I_{SOFT\ START} (mA) = C_{OUT} (\mu F) \times 0.07 (V/\mu s) + I_{LOAD} (mA) \quad (1)$$

[Equation 1](#) shows that soft-start current is directly proportional to C_{OUT} .

The output voltage ramp rate is independent of C_{OUT} and load current, and has a typical value of 0.07 V/ μ s.

Feature Description (continued)

The TPS727xx automatically adjusts the soft-start current to supply both the load current and the C_{OUT} charge current. For example, if $I_{LOAD} = 0$ mA upon enabling the LDO, $I_{SOFT\ START} = 1\ \mu\text{F} \times 0.07\ \text{V}/\mu\text{s} + 0\ \text{mA} = 70\ \text{mA}$, the current that charges the output capacitor.

If $I_{LOAD} = 200\ \text{mA}$, $I_{SOFT\ START} = 1\ \mu\text{F} \times 0.07\ \text{V}/\mu\text{s} + 200\ \text{mA} = 270\ \text{mA}$, the current required for charging output capacitor and supplying the load current.

If the output capacitor and load are increased such that the soft-start current exceeds the output current limit, the current is clamped at the typical current limit of 400 mA. For example, if $C_{OUT} = 10\ \mu\text{F}$ and $I_{OUT} = 200\ \text{mA}$, $10\ \mu\text{F} \times 0.07\ \text{V}/\mu\text{s} + 200\ \text{mA} = 900\ \text{mA}$ is not supplied. Instead, the current is clamped at 400 mA.

7.3.3 Shutdown

The enable pin (EN) is active high and is compatible with standard and low voltage, TTL-CMOS levels. When shutdown capability is not required, EN can be connected to the IN pin.

7.3.4 Dropout Voltage

The TPS727xx uses a PMOS pass transistor to achieve low dropout. When $(V_{IN} - V_{OUT})$ is less than the dropout voltage (V_{DO}), the PMOS pass device is in the linear region of operation and the input-to-output resistance is the $R_{DS(ON)}$ of the PMOS pass element. V_{DO} approximately scales with output current because the PMOS device functions like a resistor in dropout.

As with any linear regulator, PSRR and transient response are degraded as $(V_{IN} - V_{OUT})$ approaches dropout. This effect is shown in [Figure 15](#) in the [Typical Characteristics](#) section.

7.3.5 Undervoltage Lock-out (UVLO)

The TPS727xx uses an undervoltage lock-out circuit that keeps the output shut off until the input voltage reaches the UVLO threshold voltage.

7.3.6 Thermal Protection

Thermal protection disables the output when the junction temperature rises to approximately +160°C, allowing the device to cool. When the junction temperature cools to approximately +140°C the output circuitry is again enabled. Depending on power dissipation, thermal resistance, and ambient temperature, the thermal protection circuit may cycle on and off. This cycling limits the dissipation of the regulator, protecting it from damage as a result of overheating.

Any tendency to activate the thermal protection circuit indicates excessive power dissipation or an inadequate heatsink. For reliable operation, limit junction temperature to +125°C maximum. To estimate the margin of safety in a complete design (including heatsink), increase the ambient temperature until the thermal protection is triggered; use worst-case loads and signal conditions. For good reliability, thermal protection triggers at least +35°C above the maximum expected ambient condition of a particular application. This configuration produces a worst-case junction temperature of +125°C at the highest expected ambient temperature and worst-case load.

The internal protection circuitry of the TPS727xx is designed to protect against overload conditions. This circuitry is not intended to replace proper heatsinking. Continuously running the TPS727xx into thermal shutdown degrades device reliability.

7.4 Device Functional Modes

7.4.1 Operation with EN Control

Driving EN over 0.9 V turns on the regulator. Driving EN below 0.4 V puts the regulator into shutdown mode, thus reducing the operating current to 120 nA, nominal.

8 Applications and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

The TPS727xx family of low-dropout (LDO) linear regulators are ultralow quiescent current LDOs with excellent line and ultra-fast load transient performance and are designed for power-sensitive applications.

8.2 Typical Application

8.2.1 TPS72718YFF 2.5 V_{IN} to 1.8 V_{OUT} at 200 mA

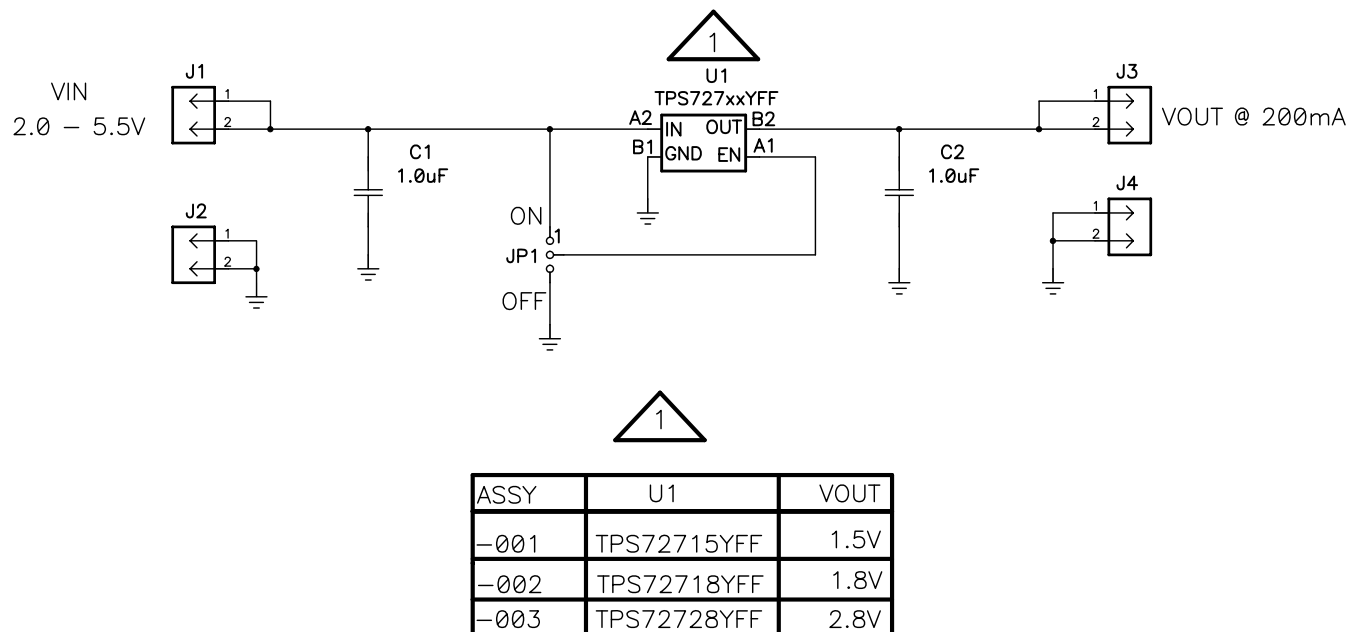


Figure 25. TPS727xxYFFEVM-407 Schematic

8.2.1.1 Design Requirements

8.2.1.1.1 Input and Output Capacitor Requirements

Although an input capacitor is not required for stability, good analog design practice is to connect a 0.1-µF to 1.0-µF low equivalent series resistance (ESR) capacitor across the IN pin and GND input of the regulator. This capacitor counteracts reactive input sources and improves transient response, noise rejection, and ripple rejection. A higher-value capacitor may be necessary if large, fast rise-time load transients are anticipated, or if the device is not located close to the power source. If source impedance is not sufficiently low, a 0.1-µF input capacitor may be necessary to ensure stability.

The TPS727xx is designed to be stable with standard ceramic capacitors with values of 1.0 µF or larger at the output. X5R- and X7R-type capacitors are best because they have minimal variation in value and ESR over temperature. Maximum ESR must be less than 200 mΩ.

8.2.1.1.2 Transient Response

As with any regulator, increasing the size of the output capacitor reduces over- and undershoot magnitude but increases duration of the transient response.

Typical Application (continued)

8.2.1.2 Detailed Design Procedure

Select the desired device based on the output voltage.

Provide an input supply with adequate headroom to include dropout and output current to account for the GND pin current and to power the load.

Select adequate input and output capacitors.

The startup current is given by [Equation 2](#):

$$I_{\text{SOFT START}} (\text{mA}) = C_{\text{OUT}} (\mu\text{F}) \times 0.07 (\text{V}/\mu\text{s}) + I_{\text{LOAD}} (\text{mA}) \quad (2)$$

[Equation 2](#) shows that soft-start current is directly proportional to C_{OUT} .

The output voltage ramp rate is independent of C_{OUT} and load current and has a typical value of 0.07 V/ μ s.

The TPS727xx automatically adjusts the soft-start current to supply both the load current and the C_{OUT} charge current. For example, if $I_{\text{LOAD}} = 0$ mA upon enabling the LDO, $I_{\text{SOFT START}} = 1 \mu\text{F} \times 0.07 \text{ V}/\mu\text{s} + 0 \text{ mA} = 70 \text{ mA}$, the current that charges the output capacitor.

If $I_{\text{LOAD}} = 200$ mA, $I_{\text{SOFT START}} = 1 \mu\text{F} \times 0.07 \text{ V}/\mu\text{s} + 200 \text{ mA} = 270 \text{ mA}$, the current required for charging output capacitor and supplying the load current.

If the output capacitor and load are increased such that the soft-start current exceeds the output current limit, the current is clamped at the typical current limit of 400 mA. For example, if $C_{\text{OUT}} = 10 \mu\text{F}$ and $I_{\text{OUT}} = 200$ mA, $10 \mu\text{F} \times 0.07 \text{ V}/\mu\text{s} + 200 \text{ mA} = 900 \text{ mA}$ is not supplied. Instead, the current is clamped at 400 mA.

Typical Application (continued)

8.2.1.3 Application Curves

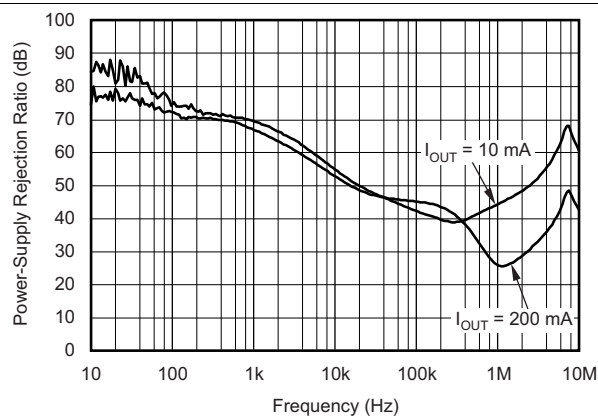
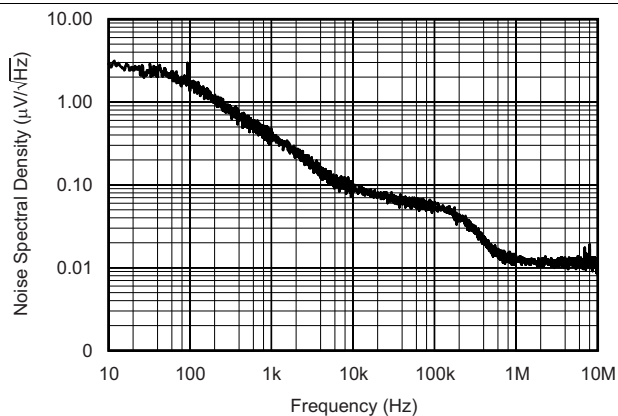
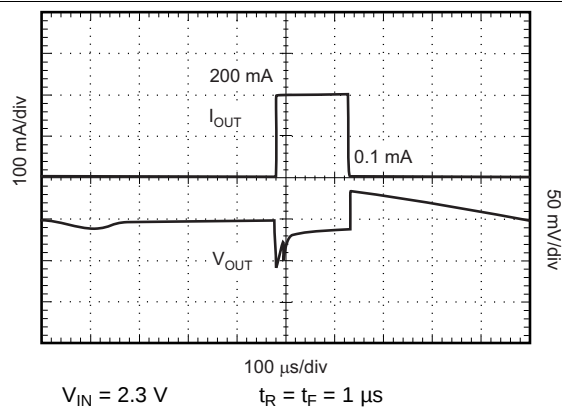


Figure 26. PSRR vs Frequency
($V_{IN} - V_{OUT} = 0.5$ V, TPS72718)



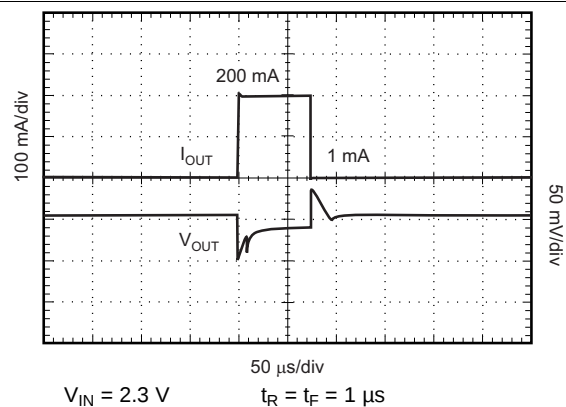
$I_{OUT} = 10$ mA $C_{IN} = C_{OUT} = 1$ μF

Figure 27. Output Spectral Noise Density vs Output Voltage
(TPS72718)



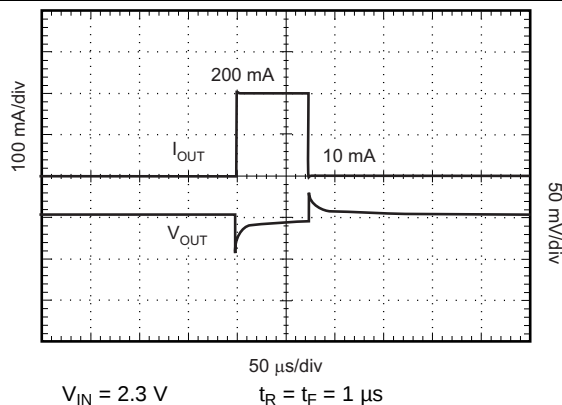
$V_{IN} = 2.3$ V $t_R = t_F = 1$ μs

Figure 28. Load Transient Response: 0.1 mA to 200 mA
(TPS72718)



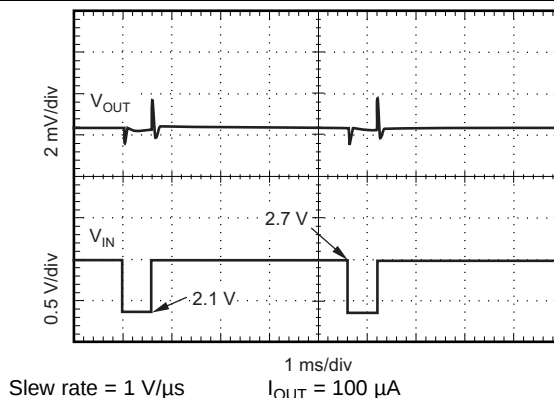
$V_{IN} = 2.3$ V $t_R = t_F = 1$ μs

Figure 29. Load Transient Response: 1 mA to 200 mA
(TPS72718)



$V_{IN} = 2.3$ V $t_R = t_F = 1$ μs

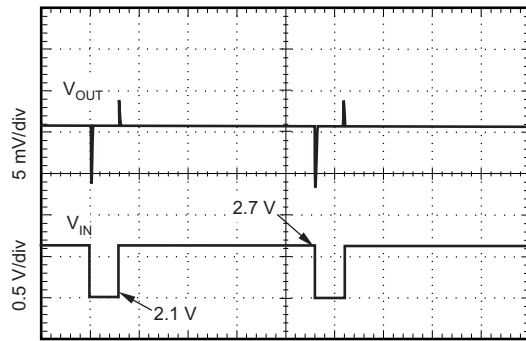
Figure 30. Load Transient Response: 10 mA to 200 mA
(TPS72718)



Slew rate = 1 V/μs $I_{OUT} = 100$ μA

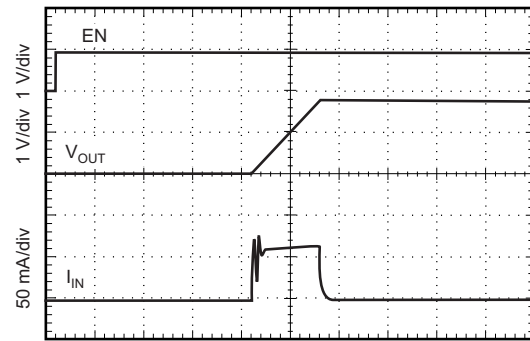
Figure 31. Line Transient Response (TPS72718)

Typical Application (continued)



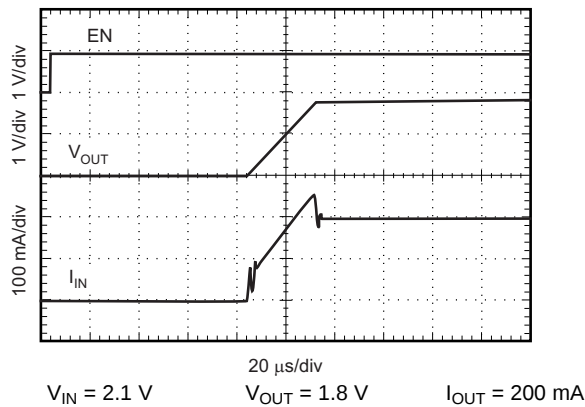
Slew rate = 1 V/μs
 $I_{OUT} = 200 \mu A$

Figure 32. Line Transient Response (TPS72718)



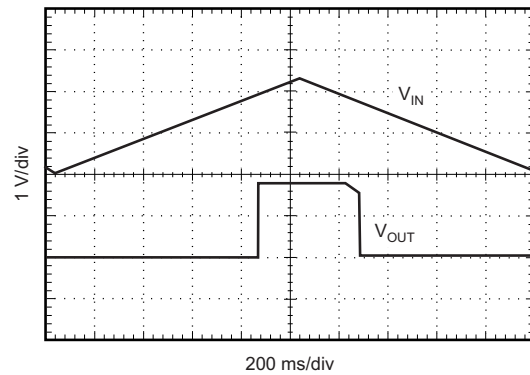
$V_{IN} = 2.1 V$
 $V_{OUT} = 1.8 V$
 $I_{OUT} = 100 \mu A$

Figure 33. V_{IN} Inrush Current (TPS72718)



$V_{IN} = 2.1 V$
 $V_{OUT} = 1.8 V$
 $I_{OUT} = 200 mA$

Figure 34. V_{IN} Inrush Current (TPS72718)



$I_{OUT} = 200 mA$

Figure 35. V_{IN} Ramp Up, Ramp Down Response (TPS72718)

8.3 Do's and Don'ts

Do place at least one 1.0-μF ceramic capacitor as close as possible to the OUT pin of the regulator.

Do not place the output capacitor more than 10 mm away from the regulator.

For DSE devices, do tie the NC pins to ground to improve thermal dissipation.

Do connect a 0.1-μF to 1.0-μF low equivalent series resistance (ESR) capacitor across the IN pin and GND input of the regulator.

Do not exceed the absolute maximum ratings.

9 Power-Supply Recommendations

These devices are designed to operate from an input voltage supply range between 2.0 V and 5.5 V. The input voltage range provides adequate headroom in order for the device to have a regulated output. This input supply must be well regulated. If the input supply is noisy, additional input capacitors with low ESR can help improve the output noise performance.

10 Layout

10.1 Layout Guidelines

10.1.1 Board Layout Recommendations to Improve PSRR and Noise Performance

To improve ac performance (such as PSRR, output noise, and transient response), TI recommends that the board be designed with separate ground planes for V_{IN} and V_{OUT} , with the ground plane connected only at the GND pin of the device. In addition, the ground connection for the output capacitor must be connected directly to the GND pin of the device. High ESR capacitors may degrade PSRR.

10.1.2 Power Dissipation

The ability to remove heat from the die is different for each package type, presenting different considerations in the printed circuit board (PCB) layout. The PCB area around the device that is free of other components moves the heat from the device to the ambient air. Performance data for JEDEC low- and high-K boards are given in the [Thermal Information](#) table. Using heavier copper increases the effectiveness in removing heat from the device. The addition of plated through-holes to heat-dissipating layers also improves the heatsink effectiveness.

Power dissipation depends on input voltage and load conditions. Power dissipation (P_D) is equal to the product of the output current times the voltage drop across the output pass element (V_{IN} to V_{OUT}), as shown in [Equation 3](#):

$$P_D = (V_{IN} - V_{OUT}) \times I_{OUT} \quad (3)$$

10.1.3 Package Mounting

Solder pad footprint recommendations and recommended land patterns are attached to the end of this document.

10.2 Layout Example

10.2.1 DSE EVM Board Layout

This section provides the TPS727xxDSEEVm-406 board layout and illustrations.

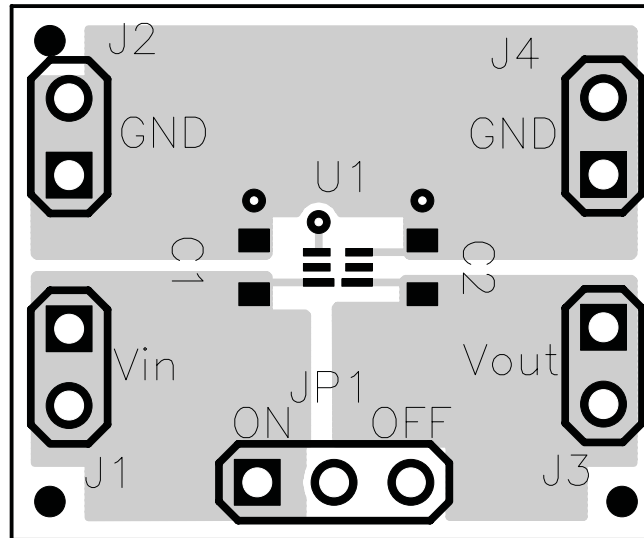


Figure 36. Top Layer Assembly

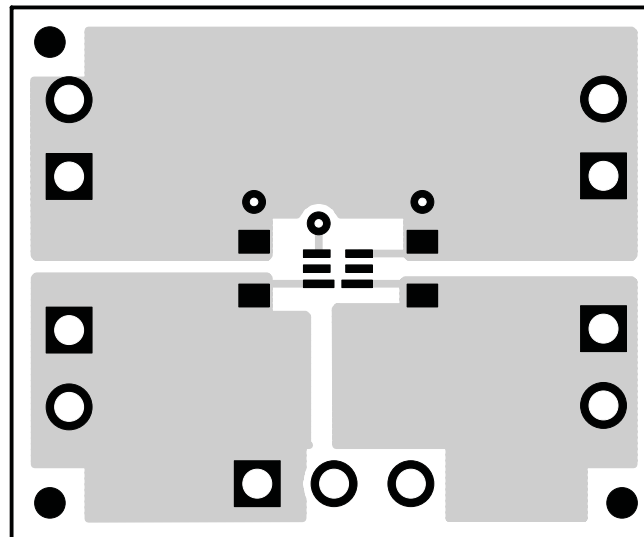


Figure 37. Top Layer Routing

Layout Example (continued)

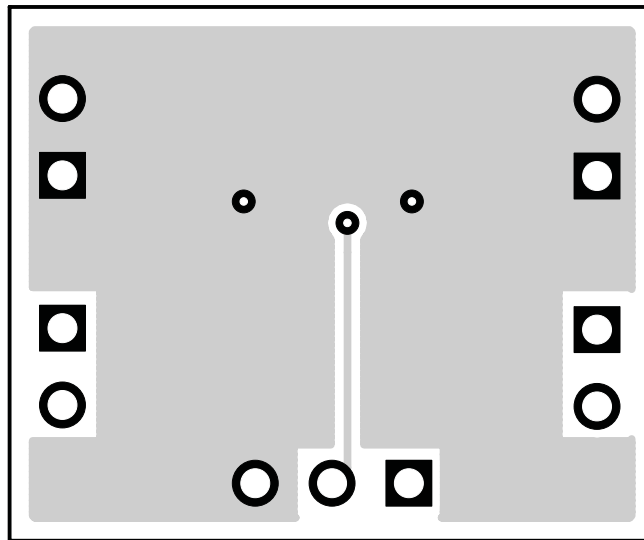


Figure 38. Bottom Layer Routing

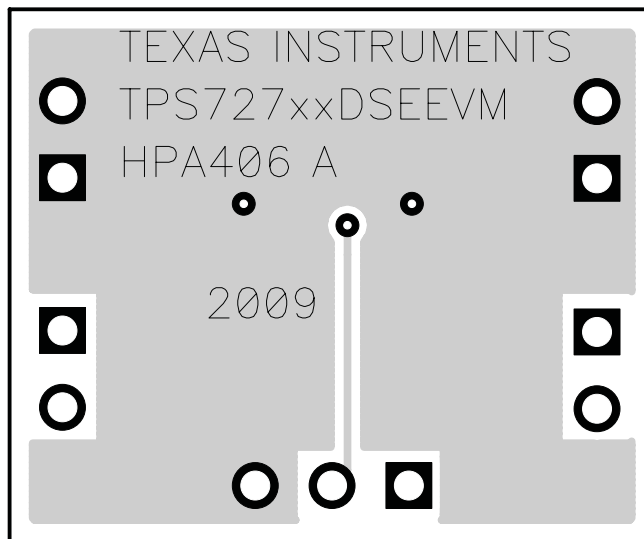


Figure 39. Bottom Layer Assembly

Layout Example (continued)

10.2.2 YFF EVM Board Layout

This section provides the TPS727xxYFFEVM-407 board layout and illustrations.

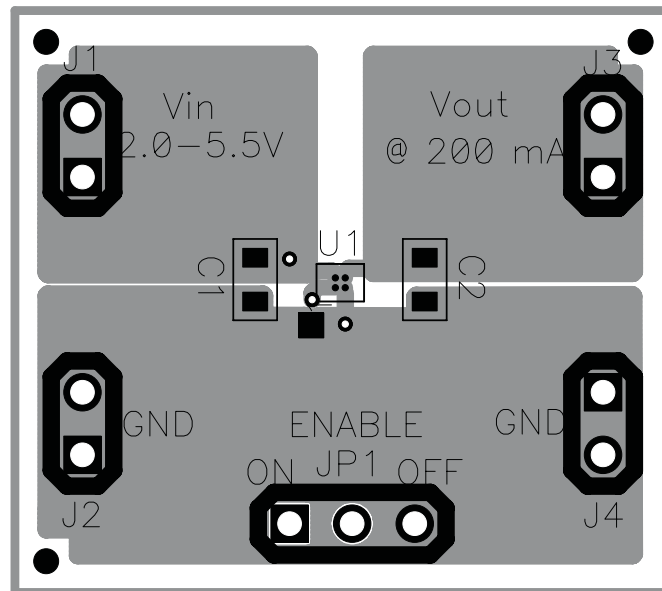


Figure 40. Top Layer Assembly

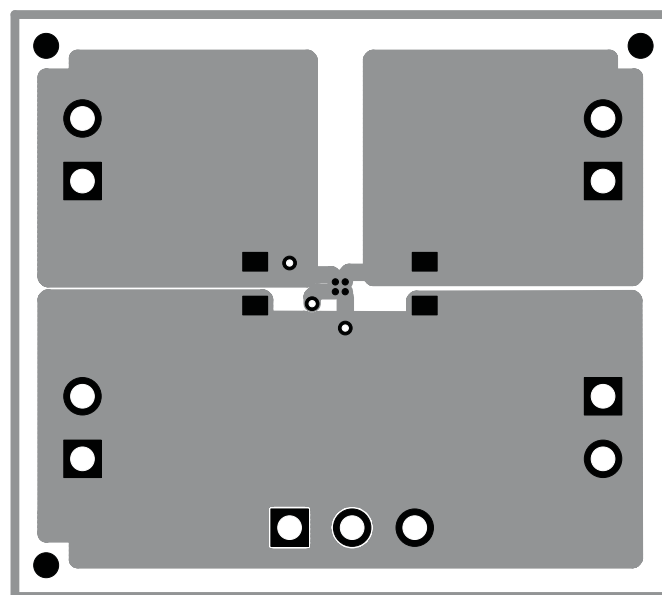


Figure 41. Top Layer Routing

Layout Example (continued)

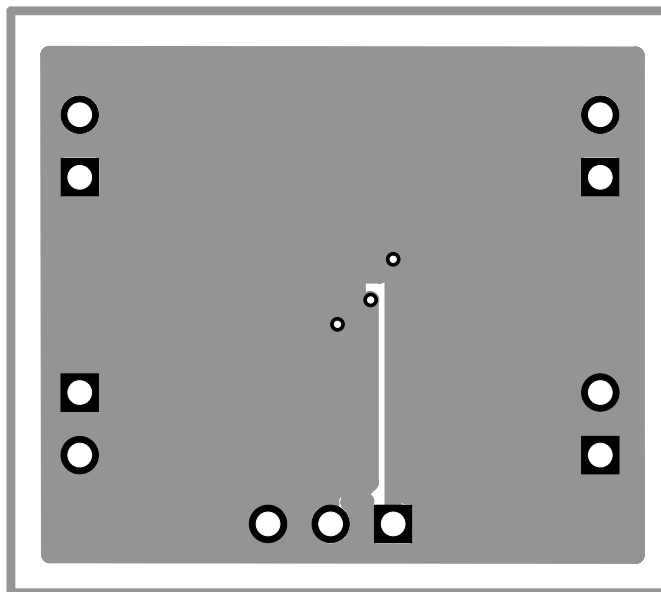


Figure 42. Bottom Layer Routing

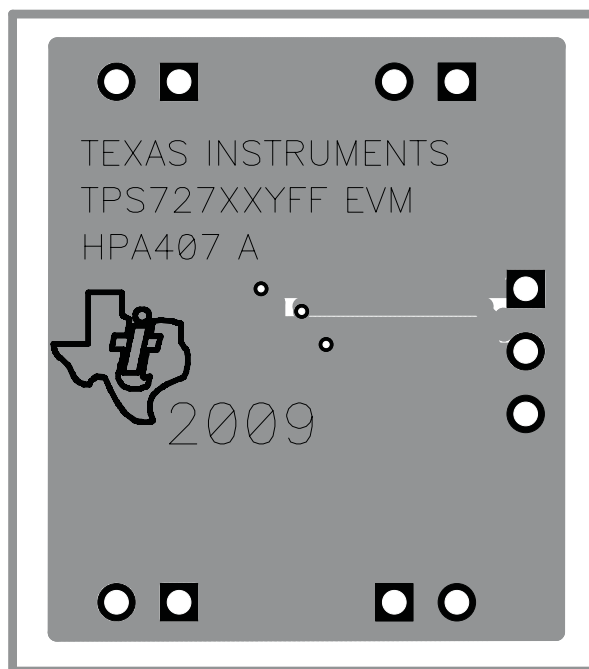


Figure 43. Bottom Layer Assembly

11 Device and Documentation Support

11.1 Documentation Support

11.1.1 Related Documentation

Application report [SLAA414](#), *LDO PSRR Measurement Simplified*.

Application report [SLAA412](#), *LDO Noise Demystified*.

User guide [SLVU323](#), *TPS727xxYFF EVM*

User guide [SLVU325](#), *TPS727xxDSE EVM*

11.1.2 Device Nomenclature

Table 1. Device Nomenclature⁽¹⁾

PRODUCT	V _{OUT} ⁽²⁾
TPS727xxx yyy z	XXX is the nominal output voltage. YYY is package designator. Z is package tape and reel quantity (R = 3000, T = 250).

- (1) For the most current package and ordering information see the Package Option Addendum at the end of this document, or visit the device product folder at www.ti.com.
- (2) Output voltages from 0.9 V to 5.0 V in 50-mV increments are available through the use of innovative factory EEPROM programming; minimum order quantities may apply. Contact factory for details and availability.

11.2 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 2. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
TPS72710	Click here	Click here	Click here	Click here	Click here
TPS727105	Click here	Click here	Click here	Click here	Click here
TPS72711	Click here	Click here	Click here	Click here	Click here
TPS72715	Click here	Click here	Click here	Click here	Click here
TPS727185	Click here	Click here	Click here	Click here	Click here
TPS72718	Click here	Click here	Click here	Click here	Click here
TPS72719	Click here	Click here	Click here	Click here	Click here
TPS72725	Click here	Click here	Click here	Click here	Click here
TPS72727	Click here	Click here	Click here	Click here	Click here
TPS727285	Click here	Click here	Click here	Click here	Click here
TPS72728	Click here	Click here	Click here	Click here	Click here
TPS72730	Click here	Click here	Click here	Click here	Click here
TPS72733	Click here	Click here	Click here	Click here	Click here
TPS72748	Click here	Click here	Click here	Click here	Click here
TPS72750	Click here	Click here	Click here	Click here	Click here

11.3 Trademarks

Bluetooth is a registered trademark of Bluetooth SIG.

Zigbee is a registered trademark of Zigbee Alliance.

All other trademarks are the property of their respective owners.

11.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

11.5 Glossary

[SLYZ022](#) — *TI Glossary*.

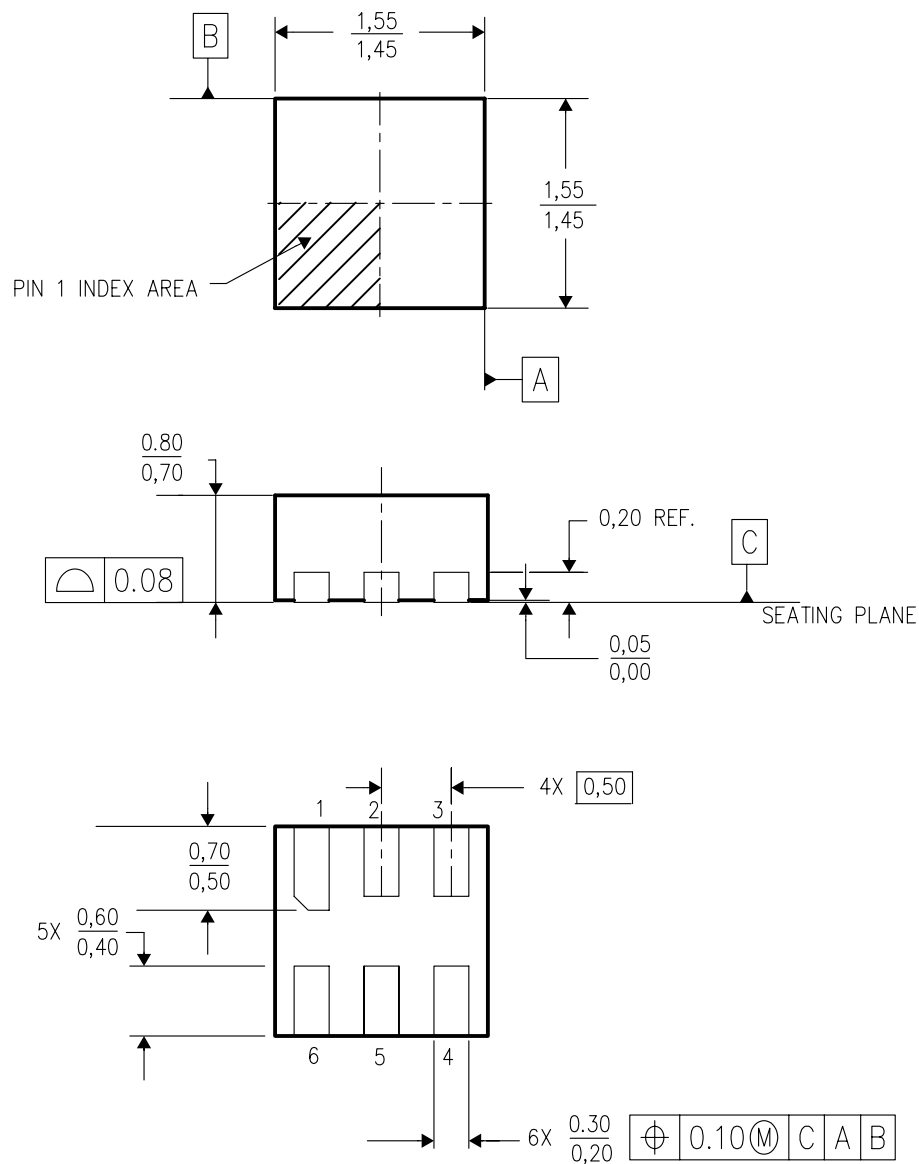
This glossary lists and explains terms, acronyms, and definitions.

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

DSE (S-PDSO-N6)

PLASTIC SMALL OUTLINE

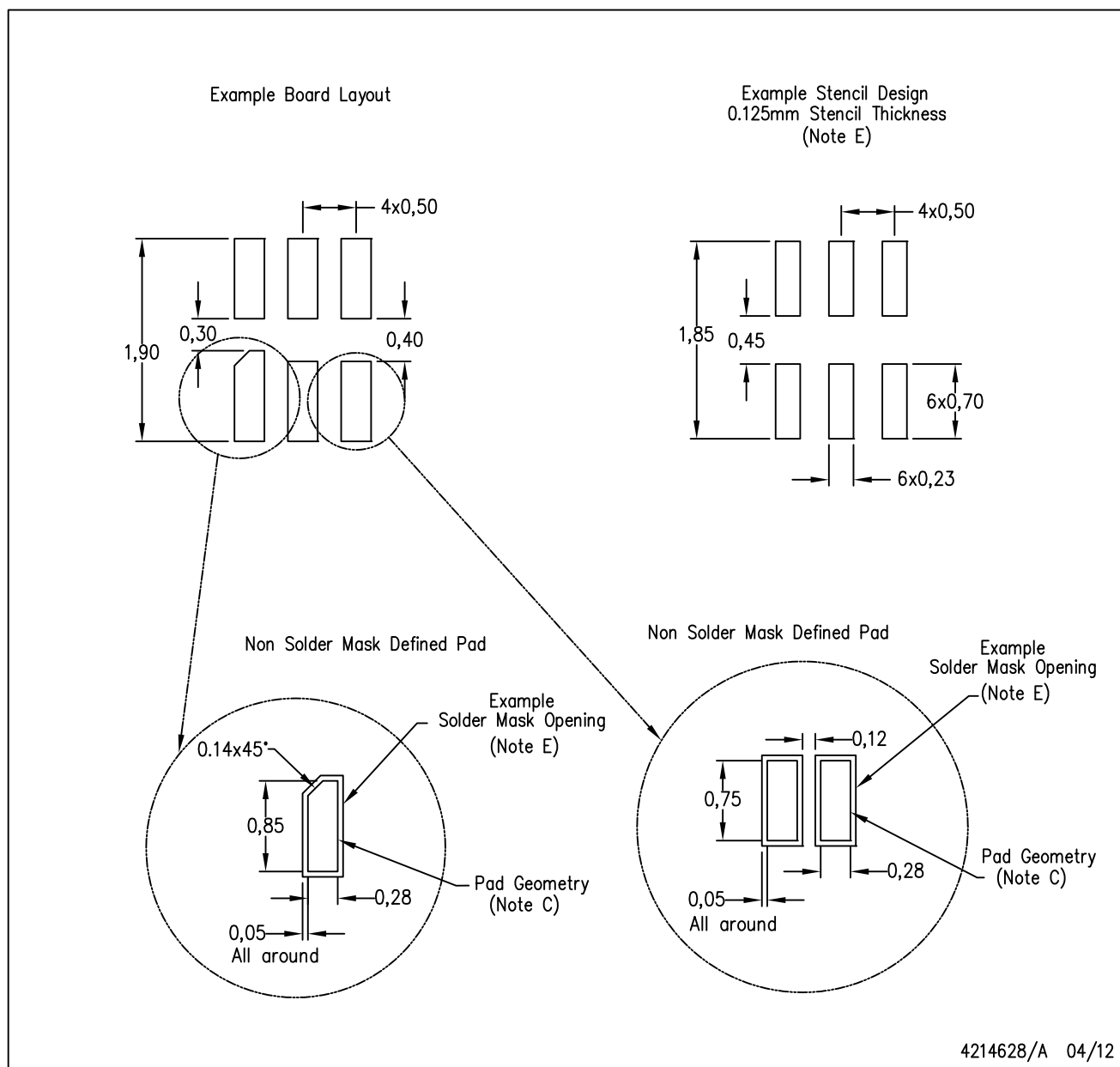


4207810/A 03/06

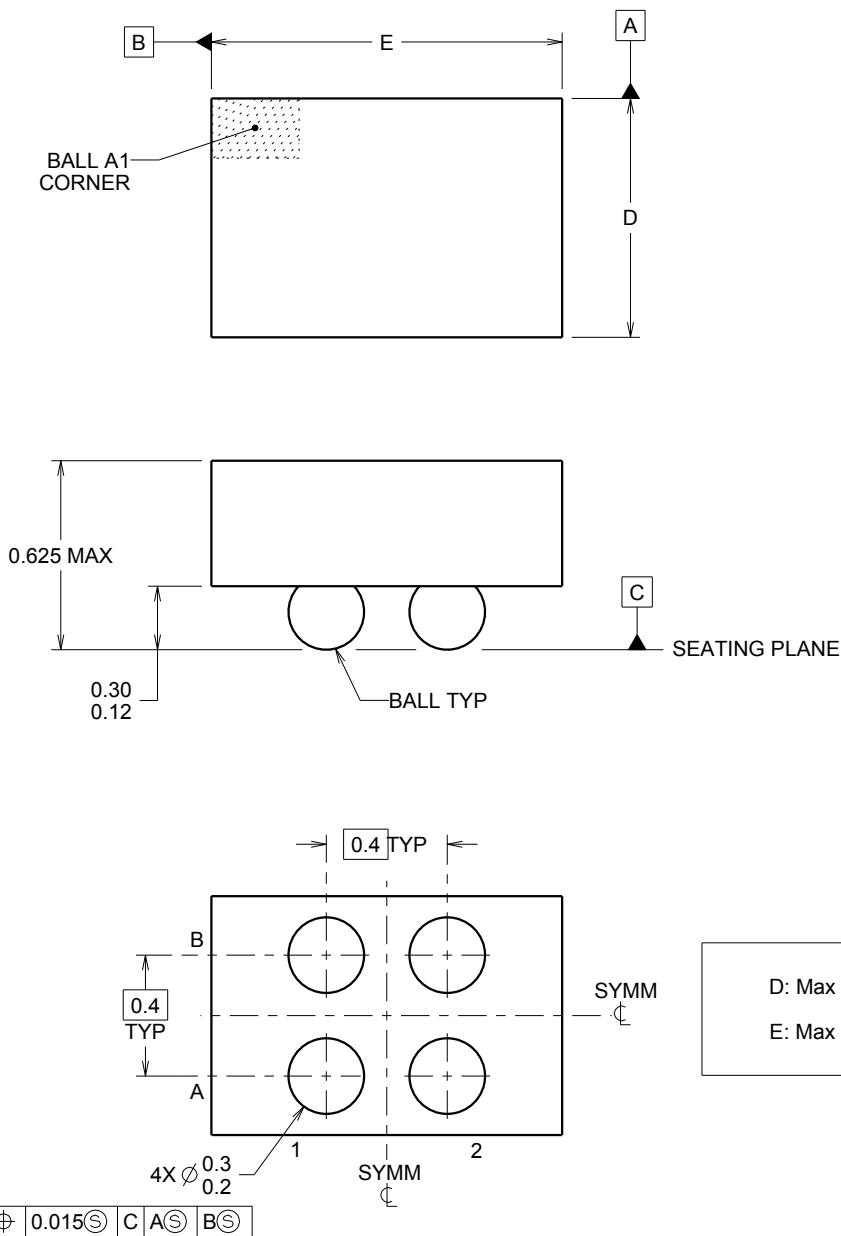
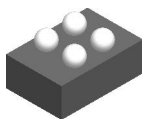
- NOTES:
- All linear dimensions are in millimeters.
 - This drawing is subject to change without notice.
 - Small Outline No-Lead (SON) package configuration.
 - This package is lead-free.

DSE (S-PWSON-N6)

PLASTIC SMALL OUTLINE NO-LEAD



- NOTES:
- All linear dimensions are in millimeters.
 - This drawing is subject to change without notice.
 - Publication IPC-7351 is recommended for alternate designs.
 - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
 - Customers should contact their board fabrication site for solder mask tolerances.

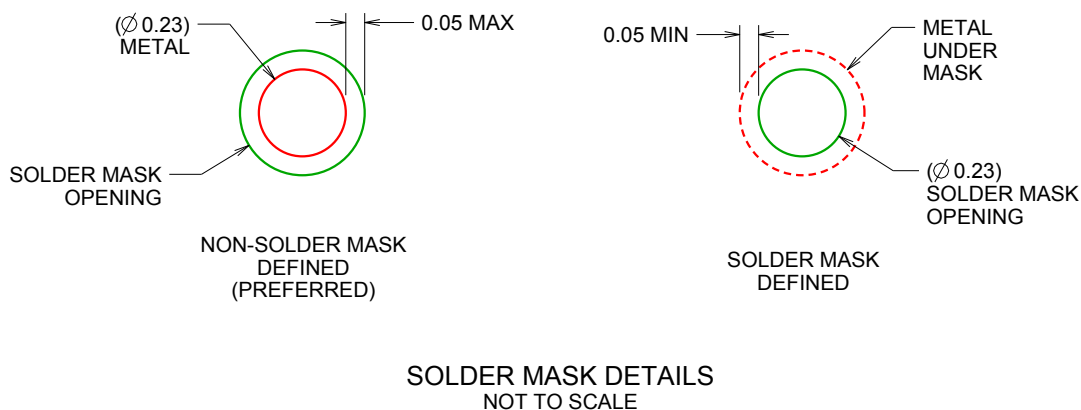
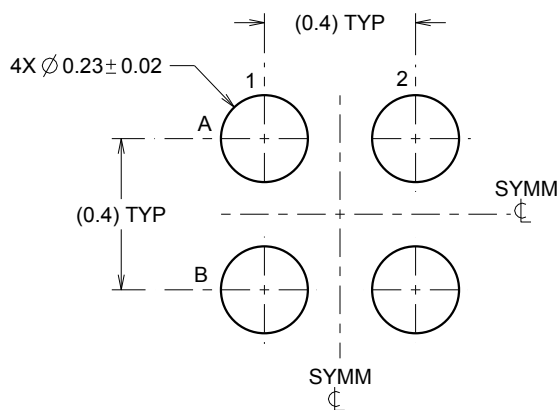


02/2014

NOTES:

NanoFree Is a trademark of Texas Instruments.

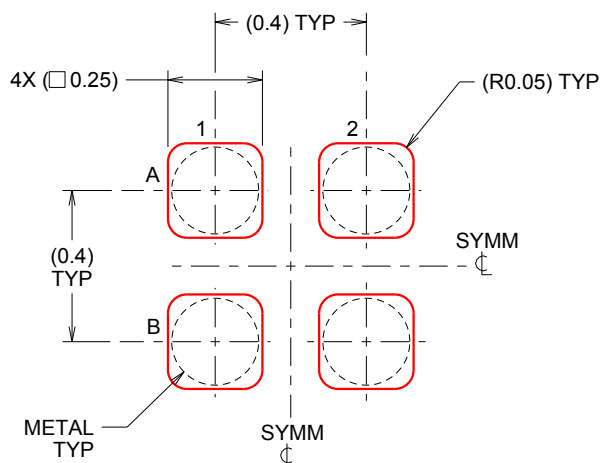
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. NanoFree™ package configuration.



02/2014

NOTES: (continued)

4. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints.
Refer to Texas Instruments Literature No. SBVA017 (www.ti.com/lit/sbva017).



SOLDER PASTE EXAMPLE
 BASED ON 0.1 mm THICK STENCIL
 SCALE:50X

02/2014

NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TPS727105YFFR	ACTIVE	DSBGA	YFF	4	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 125	GA	Samples
TPS727105YFFT	ACTIVE	DSBGA	YFF	4	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 125	GA	Samples
TPS72710DSER	ACTIVE	WSON	DSE	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	UR	Samples
TPS72710DSET	ACTIVE	WSON	DSE	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	UR	Samples
TPS72711YFFR	ACTIVE	DSBGA	YFF	4	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 125	QL	Samples
TPS72711YFFT	ACTIVE	DSBGA	YFF	4	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 125	QL	Samples
TPS72715DSER	ACTIVE	WSON	DSE	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	GS	Samples
TPS72715DSET	ACTIVE	WSON	DSE	6	250	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	GS	Samples
TPS72715YFFR	ACTIVE	DSBGA	YFF	4	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 125	GS	Samples
TPS72715YFFT	ACTIVE	DSBGA	YFF	4	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 125	GS	Samples
TPS727185YFFR	ACTIVE	DSBGA	YFF	4	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 125	RW	Samples
TPS727185YFFT	ACTIVE	DSBGA	YFF	4	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 125	RW	Samples
TPS72718DSER	ACTIVE	WSON	DSE	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	GT	Samples
TPS72718DSET	ACTIVE	WSON	DSE	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	GT	Samples
TPS72718YFFR	ACTIVE	DSBGA	YFF	4	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 125	GT	Samples
TPS72718YFFT	ACTIVE	DSBGA	YFF	4	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 125	GT	Samples
TPS72719DSER	ACTIVE	WSON	DSE	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	CB	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TPS72719DSET	ACTIVE	WSON	DSE	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	CB	Samples
TPS72719YFFR	ACTIVE	DSBGA	YFF	4	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 125	AA	Samples
TPS72719YFFT	ACTIVE	DSBGA	YFF	4	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 125	AA	Samples
TPS72725DSER	ACTIVE	WSON	DSE	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	QA	Samples
TPS72725DSET	ACTIVE	WSON	DSE	6	250	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	QA	Samples
TPS72727DSER	ACTIVE	WSON	DSE	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	TS	Samples
TPS72727DSET	ACTIVE	WSON	DSE	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	TS	Samples
TPS727285DSER	ACTIVE	WSON	DSE	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	QK	Samples
TPS727285DSET	ACTIVE	WSON	DSE	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	QK	Samples
TPS72728DSER	ACTIVE	WSON	DSE	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	GU	Samples
TPS72728DSET	ACTIVE	WSON	DSE	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	GU	Samples
TPS72728YFFR	ACTIVE	DSBGA	YFF	4	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 125	GU	Samples
TPS72728YFFT	ACTIVE	DSBGA	YFF	4	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 125	GU	Samples
TPS72730DSER	ACTIVE	WSON	DSE	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	QB	Samples
TPS72730DSET	ACTIVE	WSON	DSE	6	250	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	QB	Samples
TPS72730YFFR	ACTIVE	DSBGA	YFF	4	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 125	ZZ	Samples
TPS72730YFFT	ACTIVE	DSBGA	YFF	4	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 125	ZZ	Samples
TPS72733DSER	ACTIVE	WSON	DSE	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	QC	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TPS72733DSET	ACTIVE	WSO	DSE	6	250	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	QC	Samples
TPS72733YFFR	ACTIVE	DSBGA	YFF	4	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 125	ZY	Samples
TPS72733YFFT	ACTIVE	DSBGA	YFF	4	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 125	ZY	Samples
TPS72748YFFR	ACTIVE	DSBGA	YFF	4	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 125	EY	Samples
TPS72748YFFT	ACTIVE	DSBGA	YFF	4	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 125	EY	Samples
TPS72750YFFR	ACTIVE	DSBGA	YFF	4	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 125	CA	Samples
TPS72750YFFT	ACTIVE	DSBGA	YFF	4	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 125	CA	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "-" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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TAPE AND REEL INFORMATION


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS727105YFFR	DSBGA	YFF	4	3000	180.0	8.4	0.89	1.26	0.69	4.0	8.0	Q1
TPS727105YFFT	DSBGA	YFF	4	250	180.0	8.4	0.89	1.26	0.69	4.0	8.0	Q1
TPS72710DSER	WSON	DSE	6	3000	179.0	8.4	1.8	1.8	1.0	4.0	8.0	Q2
TPS72710DSET	WSON	DSE	6	250	179.0	8.4	1.8	1.8	1.0	4.0	8.0	Q2
TPS72711YFFR	DSBGA	YFF	4	3000	180.0	8.4	0.89	1.26	0.69	4.0	8.0	Q1
TPS72711YFFT	DSBGA	YFF	4	250	180.0	8.4	0.89	1.26	0.69	4.0	8.0	Q1
TPS72715DSER	WSON	DSE	6	3000	179.0	8.4	1.8	1.8	1.0	4.0	8.0	Q2
TPS72715DSET	WSON	DSE	6	250	179.0	8.4	1.8	1.8	1.0	4.0	8.0	Q2
TPS72715YFFR	DSBGA	YFF	4	3000	180.0	8.4	0.89	1.26	0.69	4.0	8.0	Q2
TPS72715YFFT	DSBGA	YFF	4	250	180.0	8.4	0.89	1.26	0.69	4.0	8.0	Q2
TPS727185YFFR	DSBGA	YFF	4	3000	180.0	8.4	0.89	1.26	0.69	4.0	8.0	Q1
TPS727185YFFT	DSBGA	YFF	4	250	180.0	8.4	0.89	1.26	0.69	4.0	8.0	Q1
TPS72718DSER	WSON	DSE	6	3000	179.0	8.4	1.8	1.8	1.0	4.0	8.0	Q2
TPS72718DSET	WSON	DSE	6	250	179.0	8.4	1.8	1.8	1.0	4.0	8.0	Q2
TPS72718YFFR	DSBGA	YFF	4	3000	180.0	8.4	0.89	1.26	0.69	4.0	8.0	Q2
TPS72718YFFT	DSBGA	YFF	4	250	180.0	8.4	0.89	1.26	0.69	4.0	8.0	Q2
TPS72719DSER	WSON	DSE	6	3000	179.0	8.4	1.8	1.8	1.0	4.0	8.0	Q2
TPS72719DSET	WSON	DSE	6	250	179.0	8.4	1.8	1.8	1.0	4.0	8.0	Q2

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS72719YFFR	DSBGA	YFF	4	3000	180.0	8.4	0.89	1.26	0.69	4.0	8.0	Q1
TPS72719YFFT	DSBGA	YFF	4	250	180.0	8.4	0.89	1.26	0.69	4.0	8.0	Q1
TPS72725DSER	WSO	DSE	6	3000	179.0	8.4	1.8	1.8	1.0	4.0	8.0	Q2
TPS72725DSET	WSO	DSE	6	250	179.0	8.4	1.8	1.8	1.0	4.0	8.0	Q2
TPS72727DSER	WSO	DSE	6	3000	179.0	8.4	1.8	1.8	1.0	4.0	8.0	Q2
TPS72727DSET	WSO	DSE	6	250	179.0	8.4	1.8	1.8	1.0	4.0	8.0	Q2
TPS727285DSER	WSO	DSE	6	3000	179.0	8.4	1.8	1.8	1.0	4.0	8.0	Q2
TPS727285DSET	WSO	DSE	6	250	179.0	8.4	1.8	1.8	1.0	4.0	8.0	Q2
TPS72728DSER	WSO	DSE	6	3000	179.0	8.4	1.8	1.8	1.0	4.0	8.0	Q2
TPS72728DSET	WSO	DSE	6	250	179.0	8.4	1.8	1.8	1.0	4.0	8.0	Q2
TPS72728YFFR	DSBGA	YFF	4	3000	180.0	8.4	0.89	1.26	0.69	4.0	8.0	Q2
TPS72728YFFT	DSBGA	YFF	4	250	180.0	8.4	0.89	1.26	0.69	4.0	8.0	Q2
TPS72730DSER	WSO	DSE	6	3000	179.0	8.4	1.8	1.8	1.0	4.0	8.0	Q2
TPS72730DSET	WSO	DSE	6	250	179.0	8.4	1.8	1.8	1.0	4.0	8.0	Q2
TPS72730YFFR	DSBGA	YFF	4	3000	180.0	8.4	0.89	1.26	0.69	4.0	8.0	Q1
TPS72730YFFT	DSBGA	YFF	4	250	180.0	8.4	0.89	1.26	0.69	4.0	8.0	Q1
TPS72733DSER	WSO	DSE	6	3000	179.0	8.4	1.8	1.8	1.0	4.0	8.0	Q2
TPS72733DSET	WSO	DSE	6	250	179.0	8.4	1.8	1.8	1.0	4.0	8.0	Q2
TPS72733YFFR	DSBGA	YFF	4	3000	180.0	8.4	0.89	1.26	0.69	4.0	8.0	Q1
TPS72733YFFT	DSBGA	YFF	4	250	180.0	8.4	0.89	1.26	0.69	4.0	8.0	Q1
TPS72748YFFR	DSBGA	YFF	4	3000	180.0	8.4	0.89	1.26	0.69	4.0	8.0	Q2
TPS72748YFFT	DSBGA	YFF	4	250	180.0	8.4	0.89	1.26	0.69	4.0	8.0	Q2
TPS72750YFFR	DSBGA	YFF	4	3000	180.0	8.4	0.89	1.26	0.69	4.0	8.0	Q1
TPS72750YFFT	DSBGA	YFF	4	250	180.0	8.4	0.89	1.26	0.69	4.0	8.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS727105YFFR	DSBGA	YFF	4	3000	182.0	182.0	20.0
TPS727105YFFT	DSBGA	YFF	4	250	182.0	182.0	20.0
TPS72710DSER	WSO	DSE	6	3000	203.0	203.0	35.0
TPS72710DSET	WSO	DSE	6	250	203.0	203.0	35.0
TPS72711YFFR	DSBGA	YFF	4	3000	182.0	182.0	20.0
TPS72711YFFT	DSBGA	YFF	4	250	182.0	182.0	20.0
TPS72715DSER	WSO	DSE	6	3000	203.0	203.0	35.0
TPS72715DSET	WSO	DSE	6	250	203.0	203.0	35.0
TPS72715YFFR	DSBGA	YFF	4	3000	182.0	182.0	20.0
TPS72715YFFT	DSBGA	YFF	4	250	182.0	182.0	20.0
TPS727185YFFR	DSBGA	YFF	4	3000	182.0	182.0	20.0
TPS727185YFFT	DSBGA	YFF	4	250	182.0	182.0	20.0
TPS72718DSER	WSO	DSE	6	3000	203.0	203.0	35.0
TPS72718DSET	WSO	DSE	6	250	203.0	203.0	35.0
TPS72718YFFR	DSBGA	YFF	4	3000	182.0	182.0	20.0
TPS72718YFFT	DSBGA	YFF	4	250	182.0	182.0	20.0
TPS72719DSER	WSO	DSE	6	3000	203.0	203.0	35.0
TPS72719DSET	WSO	DSE	6	250	203.0	203.0	35.0
TPS72719YFFR	DSBGA	YFF	4	3000	182.0	182.0	20.0
TPS72719YFFT	DSBGA	YFF	4	250	182.0	182.0	20.0

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS72725DSER	WSON	DSE	6	3000	203.0	203.0	35.0
TPS72725DSET	WSON	DSE	6	250	203.0	203.0	35.0
TPS72727DSER	WSON	DSE	6	3000	203.0	203.0	35.0
TPS72727DSET	WSON	DSE	6	250	203.0	203.0	35.0
TPS727285DSER	WSON	DSE	6	3000	203.0	203.0	35.0
TPS727285DSET	WSON	DSE	6	250	203.0	203.0	35.0
TPS72728DSER	WSON	DSE	6	3000	203.0	203.0	35.0
TPS72728DSET	WSON	DSE	6	250	203.0	203.0	35.0
TPS72728YFFR	DSBGA	YFF	4	3000	182.0	182.0	20.0
TPS72728YFFT	DSBGA	YFF	4	250	182.0	182.0	20.0
TPS72730DSER	WSON	DSE	6	3000	203.0	203.0	35.0
TPS72730DSET	WSON	DSE	6	250	203.0	203.0	35.0
TPS72730YFFR	DSBGA	YFF	4	3000	182.0	182.0	20.0
TPS72730YFFT	DSBGA	YFF	4	250	182.0	182.0	20.0
TPS72733DSER	WSON	DSE	6	3000	203.0	203.0	35.0
TPS72733DSET	WSON	DSE	6	250	203.0	203.0	35.0
TPS72733YFFR	DSBGA	YFF	4	3000	182.0	182.0	20.0
TPS72733YFFT	DSBGA	YFF	4	250	182.0	182.0	20.0
TPS72748YFFR	DSBGA	YFF	4	3000	182.0	182.0	20.0
TPS72748YFFT	DSBGA	YFF	4	250	182.0	182.0	20.0
TPS72750YFFR	DSBGA	YFF	4	3000	182.0	182.0	20.0
TPS72750YFFT	DSBGA	YFF	4	250	182.0	182.0	20.0

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